## 26V, 4-Channel Voltage Bus and 4-Channel High-Side Current Shunt Monitor <br> NCP45495

The NCP45495 is a high-performance monolithic IC which can be used to monitor bus voltage and current on four high-voltage power supplies simultaneously. The HV bus voltages and currents are translated to a low-voltage power domain and multiplexed onto a single differential output for measurement externally by common ADCs. The NCP45495 offers programmable voltage and current gain settings and requires a minimal amount of external passives for a small cost saving solution. The device is also configurable to operate either standalone or as a pair, permitting up to eight separate HV power supplies to be monitored and measured.

## Features

- Translates and Scales Shunt and Bus Voltages up to 26 V
- Single Device Monitors Four Supplies
- May Be Paired for Monitoring Up To Eight Supplies
- Very Low Powerdown Current
- All Channels Individually Gain Programmable via $I^{2} \mathrm{C}$ Interface
- Fast Settling Time
- Real-Time Bus Voltages Valid Signal
- Adjustable Output Common-Mode Voltage
- RoHS/REACH Compliant Device


## Applications

- Computers / Notebooks / Graphics Cards
- Power Management / Power Control Loops
- Battery Chargers


ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :---: | :---: | :---: |
| NCP45495XMNTWG | QFN32 <br> (Green) | $4000 /$ <br> Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.


Figure 1. Block Diagram

Table 1. PIN DESCRIPTION

| Pin | Name | I/O | Function |
| :---: | :---: | :---: | :---: |
| 1,4,13,16 | IN_Nx | AI | Sense Resistor Sense - High Voltage |
| 2,5,12,15 | IN_Px | AI | Sense Resistor Sense +, High Voltage |
| 3,6,11,14 | BV_INx | AI | Bus Voltage Input for Voltage monitoring |
| 7,8 | IMON_INx | AI | Current Monitor Channels (High impedance input) |
| 9 | RGND | GND | Reference Ground for multiplexer and differential amplifier |
| 17 | BG_REF_OUT | AO | Buffered Bandgap Voltage Output |
| 18 | BV_REF | AI | BV_OK comparator threshold reference |
| 19 | DIFF_OUT_N | AO | Differential Output, Negative |
| 20 | DIFF_OUT_P | AO | Differential Output, Positive |
| 21,22 | ADRS[1:0] | DI | $\mathrm{I}^{2} \mathrm{C}$ Address set bits |
| 23 | SCL | DI | ${ }^{2} \mathrm{C}$ C Clock |
| 24 | SDA | DI/DO | $\mathrm{I}^{2} \mathrm{C}$ Data Signal |
| 25 | SKIP | DI | Skip Function control (see description) Mask for BV_OK. High level is $\mathrm{V}_{\mathrm{CC}}$ and low level is GND |
| 27 | VCC | PWR | Device Power |
| 28 | EN_B | DI | Device Enable. When high, places device in low-power state. |
| 29 | MUX_SEL | DI | Multiplexer Select Input |
| 30 | BV_OK | DO | Bus OK output (open-drain; high impedance = BUS OK) |
| 31 | SYNC | DO | Sync pin outputs a pulse at the beginning of every MUX_SEL sequence |
| 33 | GND | GND | Device Ground |

Table 2. MAXIMUM RATINGS

| Rating | Pins | Condition | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | VCC | GND $=0 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{CC}}$ | -0.3 to 5.5 | V |
| Bus Input Voltage Range | BV_INx, IN_Px, IN_Nx | GND $=0 \mathrm{~V}$ | $\mathrm{V}_{\text {BV_IN }}$ | -0.3 to 30 | V |
| Digital Input Voltage Range | MUX_SEL, EN_B, SKIP, SCL, $\text { SDA, ADRS }[x]$ | GND $=0 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{LV}}$ | -0.3 to 5.5 | V |
| Low Voltage I/O Range | DIFF_OUT P, DIFF_OUT_N, BV_OK, BG_REF_OUT | GND $=0 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{LV}}$ | -0.3 to 5.5 | V |
| Thermal Resistance, Junction-to-Air |  |  | $\mathrm{R}_{\text {өJA }}$ | 40 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance, Junction-to-Case ( $\mathrm{V}_{\text {IN }}$ Paddle) |  |  | $\mathrm{R}_{\text {өJC }}$ | 5 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Operating Temperature Range |  |  | $\mathrm{T}_{\mathrm{A} 1}$ | -40 to 105 | ${ }^{\circ} \mathrm{C}$ |
| Functional Temperature Range |  |  | $\mathrm{T}_{\mathrm{A} 2}$ | -40 to 125 | ${ }^{\circ} \mathrm{C}$ |
| Maximum Junction Temperature |  |  | $\mathrm{T}_{J}$ | 125 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range |  |  | $\mathrm{T}_{\text {STG }}$ | -40 to 150 | ${ }^{\circ} \mathrm{C}$ |
| Lead Temperature, Soldering (10 sec.) |  |  | $\mathrm{T}_{\text {SLD }}$ | 260 | ${ }^{\circ} \mathrm{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 3. ESD RATINGS

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| ESD Capability, Human Body Model (Note 1) | ESD $_{\text {HBM }}$ | $>2.0$ | kV |
| ESD Capability, Charged Device Model (Note 1) | ESD $_{\text {CDM }}$ | $>0.5$ | kV |

1. Tested by the following methods @ $T_{A}=25^{\circ} \mathrm{C}$

ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
ESD Charged Device Model per JESD22-C101
Table 4. RECOMMENDED OPERATING RANGES

| Rating | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | $\mathrm{V}_{\mathrm{CC}}$ | 2.8 | 3.8 | V |
| Bus Input Pin Voltage Range | $\mathrm{V}_{\text {IN_PX }}, \mathrm{V}_{\text {IN_Nx }}$ | 5 | 26 | V |
| Digital Input High Voltage Range (Note 2) | $\mathrm{V}_{\text {IH }}$ | 0.945 |  | V |
| Digital Input Low Voltage Range (Note 2) | $\mathrm{V}_{\text {IL }}$ |  | 0.405 | V |
| SKIP Input High Voltage Range | SKIP $_{\text {VIH }}$ | 2.8 | 3.8 | V |
| SKIP Input Low Voltage Range | SKIP ${ }_{\text {VIL }}$ |  | 0.405 | V |
| Ambient Temperature | $\mathrm{T}_{\mathrm{A}}$ | -40 | 85 | ${ }^{\circ} \mathrm{C}$ |
| Junction Temperature | $\mathrm{T}_{J}$ | -40 | 125 | ${ }^{\circ} \mathrm{C}$ |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.
2. $\mathrm{V}_{\mathrm{IL}}$ and $\mathrm{V}_{\mathrm{IH}}$ ranges apply to the EN_B, SCLK, SDA, ADRS[x], and MUX_SEL pins

Table 5. ELECTRICAL CHARACTERISTICS $\mathrm{V}_{\mathrm{IN}} \mathrm{PX}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN} \mathrm{B}}=0 \mathrm{~V}, \mathrm{Vcc}=3.3 \mathrm{~V}$, unless indicated otherwise. Min and Max values are valid for temperature range $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{J}}<+1 \overline{0} 5^{\circ} \mathrm{C}$ unless notēd otherwise and are guaranteed by test, design, characterization, or statistical correlation. Typical values are referenced to $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| AC CHARACTERISTICS ( $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ unless otherwise specified) |  |  |  |  |  |
| Multiplexer Settling Time (to 9.375 mV ) | T STAB1 |  |  | 100 | ns |
| Multiplexer Settling Time (to 3 mV ) | TStAB2 |  |  | 300 | ns |
| MUX_SEL Period (normal operation - assuming no timeout set) | $\mathrm{T}_{\text {MSP }}$ | 0.185 |  |  | $\mu \mathrm{s}$ |
| MUX_SEL Timeout (from falling edge of MUX_SEL) |  | 35 | 39 | 43 | $\mu \mathrm{s}$ |
| Power-up Time (STANDBY or Limited Function to Full Function) (Note 3) | TPWR_UP |  |  | 40 | $\mu \mathrm{s}$ |
| Differential Amplifier Capacitive Load Capability (Note 4) | $\mathrm{C}_{\text {DIFF }}$ |  |  | 82 | pF |

DC CHARACTERISTICS

| Input Impedance (EN_B pin tri-stated) | $\mathrm{R}_{\text {FLOAT }}$ | 100k |  |  | $\Omega$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| IMONx Channel Input Leakage Current |  |  |  | 100 | nA |
| BG_REF_OUT Voltage | $V_{B G}$ | 1.274 | 1.3 | 1.326 | V |
| BG_REF_OUT maximum loading | $\mathrm{I}_{\mathrm{BG}}$ |  |  | 100 | $\mu \mathrm{A}$ |
| BV_OK Logic Low Impedance (Note 5) | $\mathrm{R}_{\mathrm{BV} \text { _OK }}$ |  |  | 300 | $\Omega$ |
| BV_REF Voltage Range | BV_REF | 100 |  | 800 | mV |
| BV_OK Comparator Hysteresis |  | 7.5 | 10 | 12.5 | \% |
| BV_OK Comparator VBUS divide ratio |  |  | 1/32 |  | V/V |
| VCC range for BV_OK low impedance | $\mathrm{V}_{\mathrm{LI}}$ | 1 |  | 3.8 | V |
| VCC Threshold Reference for BV_OK Input (POR) (Note 6) | $\mathrm{V}_{\text {BV_TH }}$ | 2.6 |  | 2.8 | V |
| POR Hysteresis |  |  | 150 |  | mV |
| Shunt Monitor Offset Voltage, room temp (Note 7) | $\mathrm{V}_{\text {SM_OV }}$ | -150 |  | 150 | $\mu \mathrm{V}$ |
| Shunt Monitor Offset Voltage Drift (Note 7) | SM_VD |  |  | 2 | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| Shunt Monitor CMRR (V/1N_Px in valid range, see above) | SM_CMRR | 80 |  |  | dB |
| Shunt Current Gain Range (See Table 6) |  | 2 |  | 24 | $\mathrm{V} / \mathrm{V}$ |
| Shunt Current Gain Tolerance (Note 11) |  |  |  | 0.6 | \% |
| Differential Amp Input Offset Voltage, $25^{\circ} \mathrm{C}$ (Note 8) | $\mathrm{V}_{\text {D_OVRT }}$ | -2 |  | 2 | mV |
| Differential Amp Input Offset Voltage, $-40^{\circ} \mathrm{C}$ to $105^{\circ} \mathrm{C}$ (Note 8) | $\mathrm{V}_{\text {D_OVT }}$ | -6 |  | 6 | mV |
| Differential Amp PSRR ( $\mathrm{V}_{\mathrm{CC}}=2.8 \mathrm{~V}$ to 3.8 V ) | DA_PSRR | 54 |  |  | dB |
| Differential Amp Common-Mode Voltage | $\mathrm{V}_{\text {CMR }}$ | 575 |  | 875 | mV |
| Differential Amp Closed Loop Gain (Note 11) | $\mathrm{G}_{\mathrm{DA}}$ | 0.994 | 1 | 1.006 | $\mathrm{V} / \mathrm{V}$ |
| Differential Full Scale Output | $\mathrm{V}_{\mathrm{FSO}}$ |  |  | 800 | mV pp |
| I_VCC (Fully Functional, EN_B $=0$, MUX_SEL clocked at 2 MHz , VCC must be $2.8 \mathrm{~V}-3.8 \mathrm{~V}$ ) | IVcc_F |  |  | 2.0 | mA |
| I_VCC (Limited Function, EN_B=Tristate, VCC must be $2.8 \mathrm{~V}=3.8 \mathrm{~V}$ ) | Ivcc_L |  |  | 400 | $\mu \mathrm{A}$ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
3. TPWR_UP begins when EN_B goes low. After the power up time, MUX_SEL may begin clocking out data. This time also applies following any register programming.
4. Differential Output CLOAD (i.e.: DIFF_OUT_x to GND) appears as a series RC with lumped equivalent R (0.86-8.6 $\Omega$ )
5. BV_OK should be connected to a pull up resistor of value $10 \mathrm{~K} \Omega$ or greater.
6. $\mathrm{Vc} \bar{c}^{-}$detection for BV _OK must trip in this range. Device can be either Full Function or Limited Function mode in this range
7. Shunt Monitor Offset Voltage and Offset Voltage Drift are referred to the IN_Px and IN_Nx pins.
8. Differential Amplifier Input Offset Voltage is referred to the multiplexer input pins
9. $\mathrm{V}_{\mathrm{EN}}=\mathrm{V}_{\mathrm{CC}}$; Total $\mathrm{V}_{\mathrm{CC}}$ standby current is $\mathrm{IVCC}_{\mathrm{V}} \mathrm{s}$ for every IN PX channel that is not floating
10. Specifications for $\mathrm{V}_{\mathrm{BUS}}$ current draw are only applicable when $\mathrm{V}_{\mathrm{CC}}=2.8 \mathrm{~V}$ to 3.8 V .
11.3-sigma variation specification

Table 5. ELECTRICAL CHARACTERISTICS $\mathrm{V}_{\mathrm{IN}} \mathrm{px}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN} \mathrm{B}}=0 \mathrm{~V}, \mathrm{Vcc}=3.3 \mathrm{~V}$, unless indicated otherwise. Min and Max values are valid for temperature range $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{J}}<+1 \overline{0}^{\circ} \mathrm{C}$ unless notēd otherwise and are guaranteed by test, design, characterization, or statistical correlation. Typical values are referenced to $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DC CHARACTERISTICS |  |  |  |  |  |
| I_VCC (STANDBY) (Note 9) | Ivcc_s |  |  | 200 | $\mu \mathrm{A}$ |
| I_BV_IN (BV_IN current in STANDBY mode) | IBV_IN_S |  |  | 2 | $\mu \mathrm{A}$ |
| I_BV_IN (BV_IN current in LIMITED mode) | lBV_IN_L |  |  | 120 | $\mu \mathrm{A}$ |
| I_BV_IN (BV_IN current in Full Function) | IBV _IN_F |  |  | 600 | $\mu \mathrm{A}$ |
| I_BV_IN (BV_IN current when VCC = FLOATING) | $\mathrm{I}_{\text {BV_IN }}$ |  |  | 2 | $\mu \mathrm{A}$ |
| I_IN_N (IN_N current in STANDBY/LIMITED mode) (Note 10) | In_N |  |  | 1 | $\mu \mathrm{A}$ |
| I_IN_P (IN_P current in STANDBY/LIMITED mode) (Note 10) | In_P |  |  | 1 | $\mu \mathrm{A}$ |
| I_IN_N (IN_N current in Full Function mode) (Note 10) |  |  |  | 60 | $\mu \mathrm{A}$ |
| I_IN_P (IN_P current in Full Function mode mode) (Note 10) |  |  |  | 60 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {BUS }}$ Gain Range |  | 1/64 |  | 1/4 | V/V |
| $\mathrm{V}_{\text {BUS }}$ Gain Tolerance |  |  |  | 0.6 | \% |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
3. TPWR_Up begins when EN_B goes low. After the power up time, MUX_SEL may begin clocking out data. This time also applies following any register programming.
4. Differential Output CLOAD (i.e.: DIFF_OUT_x to GND) appears as a series RC with lumped equivalent $\mathrm{R}(0.86-8.6 \Omega)$
5. BV OK should be connected to a pull up resistor of value $10 \mathrm{~K} \Omega$ or greater.
6. Vcc detection for BV_OK must trip in this range. Device can be either Full Function or Limited Function mode in this range
7. Shunt Monitor Offset Voltage and Offset Voltage Drift are referred to the IN_Px and IN_Nx pins.
8. Differential Amplifier Input Offset Voltage is referred to the multiplexer input pins
9. $\mathrm{V}_{\mathrm{EN}}=\mathrm{V}_{\mathrm{CC}}$; Total $\mathrm{V}_{\mathrm{CC}}$ standby current is $\mathrm{I}_{\mathrm{VCC}}$ s for every IN _Px channel that is not floating
10. Specifications for $\mathrm{V}_{\mathrm{BUS}}$ current draw are only applicable when $\mathrm{V}_{\mathrm{CC}}=2.8 \mathrm{~V}$ to 3.8 V .
11.3-sigma variation specification

## DETAILED DESCRIPTION

Differential Output Amplifier: An integrated differential output amplifier provides a scaled representation of multiple bus voltages and currents to an external ADC on the DIFF_OUT_P and DIFF_OUT_N pins. These voltages and currents are presented sequentially (under control of the Sequence Logic block) via the Multiplexer. The gain of the differential amplifier is $1 \mathrm{~V} / \mathrm{V}$. The common-mode voltage of the differential output amplifier is established by an internal reference divider. The common mode voltage is programmable from 575 mV to 875 mV in 25 mV increments to offer flexibility for the ADC reading the differential outputs. The contents of the DIFF_AMP_CM register set the differential amplifier common mode voltage. The offset of the differential amplifier is also programmable by setting the DIFF_AMP_OFFSET register. The differential offset can be set to 0 mV or from -325 to -375 mV in 25 mV increments. See the DIFF_AMP register description in the $\mathrm{I}^{2} \mathrm{C}$ interface definition section for more details.

Shunt Current Monitor (one of four identical instances):
The differential voltage across an external sense resistor ( $\mathrm{R}_{\text {SENSE }}$ ) is converted to a current by a transconductor stage implemented by an op-amp and an internal shunt resistor $\mathrm{R}_{\mathrm{SC} 1}$. The current is forced through a programmable internal resistor $\mathrm{R}_{\mathrm{SC} 2}$ to create the internal shunt voltage. The resulting voltage is fed into the multiplexer for readout. The conversion gain can be programmed to gains from 2 x to $24 x$. The SHUNT_GAINx registers are used to set the shunt current gains for each channel. The voltage represented on the differential output for the shunt current is the voltage drop across the external sense resistor multiplied by the shunt gain.
Diff Output $=$ Iload $*$ Rsense * shunt gain

The table below shows the available shunt gain settings.
Table 6. SHUNT CURRENT PROGRAMMABLE GAIN SETTINGS

| SHUNT_GAIN (Bits 5-1) | Register Contents (includes bit 0) | Shunt Current Channel Gains |
| :---: | :---: | :---: |
| Ob'11111 | 0x3E | 24.000 |
| Ob'11110 | 0x3C | 22.151 |
| Ob'11101 | $0 \times 3 \mathrm{~A}$ | 20.445 |
| Ob'11100 | $0 \times 38$ | 18.870 |
| Ob'11011 | $0 \times 36$ | 17.417 |
| Ob'11010 | $0 \times 34$ | 16.075 |
| Ob'11001 | 0x32 | 14.837 |
| Ob'11000 | 0x30 | 13.694 |
| Ob'10111 | 0x2E | 12.639 |
| Ob'10110 | 0x2C | 11.665 |
| Ob'10101 | $0 \times 2 \mathrm{~A}$ | 10.767 |
| Ob'10100 | $0 \times 28$ | 9.937 |
| Ob'10011 | $0 \times 26$ | 9.172 |
| Ob'10010 | $0 \times 24$ | 8.465 |
| Ob'10001 | 0x22 | 7.813 |
| Ob'10000 | 0x20 | 7.212 |
| Ob'01111 | 0x1E | 6.656 |
| Ob'01110 | $0 \times 1 \mathrm{C}$ | 6.143 |
| Ob'01101 | $0 \times 1 \mathrm{~A}$ | 5.670 |
| Ob'01100 | $0 \times 18$ | 5.233 |
| Ob'01011 | $0 \times 16$ | 4.830 |
| Ob'01010 | $0 \times 14$ | 4.458 |
| Ob'01001 | $0 \times 12$ | 4.115 |
| 0b'01000 | $0 \times 10$ | 3.798 |
| Ob'00111 | 0x0E | 3.505 |
| Ob'00110 | 0x0C | 3.235 |
| Ob'00101 | $0 \times 0 \mathrm{~A}$ | 2.986 |
| Ob'00100 | $0 \times 08$ | 2.756 |
| Ob'00011 | $0 \times 06$ | 2.544 |
| Ob'00010 | $0 \times 04$ | 2.348 |
| Ob'00001 | 0x02 | 2.167 |
| Ob'00000 | $0 \times 00$ | 2.000 |

Bus Voltage Monitor (one of four identical instances): An internal voltage divider ( $\mathrm{R}_{\mathrm{BV} 1}$ and $\mathrm{R}_{\mathrm{BV} 2}$ ) is used to scale the voltage on the BV_INx pin to an appropriate full-scale range for the differential output amplifier. The voltage divider is programmable from $1 / 4(\mathrm{~V} / \mathrm{V})$ to $1 / 64(\mathrm{~V} / \mathrm{V})$ as shown in the table below. BUS_GAINx registers are used to set the voltage gains for each channel. The differential output voltage representing the bus voltage is the bus voltage divided by the VBUS attenuation.

$$
\text { Diff Output }=\frac{V_{B U S}}{A_{V}}
$$

Table 7. VBUS PROGRAMMABLE ATTENUATION SETTINGS

| BUS_GAIN <br> (Bits 5-1) | Register Contents (includes bit 0) | VBUS Attenuation Setting ( $\mathrm{A}_{\mathrm{V}}$ ) |
| :---: | :---: | :---: |
| 0b'00000 | 0x00 | 64.00 |
| Ob'00001 | 0x02 | 58.524 |
| 0b'00010 | $0 \times 04$ | 53.517 |
| 0b'00011 | $0 \times 06$ | 48.939 |
| 0b'00100 | $0 \times 08$ | 44.752 |
| 0b'00101 | 0x0A | 40.923 |
| 0b'00110 | 0x0C | 37.422 |
| Ob'00111 | 0x0E | 34.220 |
| 0b'01000 | $0 \times 10$ | 31.292 |
| 0b'01001 | $0 \times 12$ | 28.615 |
| 0b'01010 | $0 \times 14$ | 26.167 |
| Ob'01011 | $0 \times 16$ | 23.928 |
| Ob'01100 | $0 \times 18$ | 21.881 |
| Ob'01101 | $0 \times 1 \mathrm{~A}$ | 20.009 |
| Ob'01110 | $0 \times 1 \mathrm{C}$ | 18.297 |
| Ob'01111 | 0x1E | 16.732 |
| Ob'10000 | 0x20 | 15.300 |
| Ob'10001 | 0x22 | 13.991 |
| Ob'10010 | 0x24 | 12.794 |
| Ob'10011 | 0x26 | 11.700 |
| Ob'10100 | 0x28 | 10.699 |
| Ob'10101 | $0 \times 2 \mathrm{~A}$ | 9.783 |
| Ob'10110 | 0x2C | 8.946 |
| Ob'10111 | $0 \times 2 \mathrm{E}$ | 8.181 |
| Ob'11000 | 0x30 | 7.481 |
| Ob'11001 | 0x32 | 6.841 |
| Ob'11010 | $0 \times 34$ | 6.256 |
| Ob'11011 | $0 \times 36$ | 5.720 |
| Ob'11100 | $0 \times 38$ | 5.231 |
| Ob'11101 | $0 \times 3 \mathrm{~A}$ | 4.783 |
| Ob'11110 | 0x3C | 4.374 |
| Ob'11111 | 0x3E | 4.000 |

High Impedance Voltage Monitor (one of two identical instances):

The voltage on the IMON_INx pin is fed directly to the multiplexer for readout. The differential output voltage represents the voltage on the IMON_INx pin.
Multiplexer Select: The multiplexer selection is controlled by a single digital input (MUX_SEL pin). The device will monitor this pin and cycle through the different measured parameters in a fixed sequence. The sequence will repeat the cycle until either a timeout condition is detected or the device is disabled. If the timeout is disabled, then MUX_SEL must be clocked through the whole sequence before the cycle will repeat.

## MUX_SEL Timeout

The MUX_SEL timeout can be enabled or disabled over the $I^{2} \mathrm{C}$ interface. If enabled, after $45 \mu$ s of idle time on the MUX_SEL pin the MUX_SEL sequence is reset back to the beginning. All new register settings will become effective at the timeout. Writing 0b1 to the TIMEOUT register will disable the timeout. If the timeout is disabled, MUX_SEL must be clocked to complete the full sequence before the cycle will repeat.
Paired Devices: In paired operation, programmed bits in the MUX_SEL_SKIP register designate which device is "Device A" and "Device B" of a pair. Device A always goes first in the sequence. When paired, the differential output amplifiers of the two devices are expected to be "wire-or'ed" together, and the table logic insures that only one device will actively drive the output pins DIFF_OUT_P and DIFF_OUT_N at any given time. See description in the Auxiliary Functions section for details. When in paired mode, the configuration register settings for registers TIMEOUT, DIFF_AMP_OFFSET and DIFF_AMP_CM must match between the $\overline{2}$ devices.

## Power-up Sequence

Correct functionality of the power monitor is not dependent on a specific power up sequence. All used bus voltages and VCC must be powered before the output will be correct. The ACTIVE_CHAN register must be set over the $I^{2} \mathrm{C}$ interface after V $\bar{C} \mathrm{C}$ is up to set the active channel count. MUX_SEL may begin clocking out data 40us after EN_B goes low. Before the part is configured, BV_OK will function with all VBUS channels considered active. Because all VBUS channels are active by default until otherwise configured, if BV_OK functionality is used before the part is configured, un-used VBUS inputs should be tied to used VBUS inputs.

## Calibration Cycle

Setting bit 7 in the ACTIVE_CHAN register adds an additional cycle at the end of the standard MUX_SEL cycles. During this cycle, the device ground (connected to the RGND pin) is muxed through the signal chain. The
resulting differential output represents the differential amplifier offset error. The RGND pin should be treated as a reference ground. The controller can use the RGND readout to cancel out remaining offset error if desired. The calibration cycle is disabled by default. If in paired mode with 2 devices, then a calibration cycle will be added to the end of the sequence from each individual contributing device respectively. See Figure 2 and Figure 10 for CAL cycle example.

## Polarity Mode

Setting bit 7 in the ALTERNATING_MODE register puts the differential output in alternating polarity mode. In alternating polarity mode, the voltage and current readouts will be repeated with alternating differential amplifier input polarity. This allows the user to compute and cancel out any differential amplifier offset. An example of an output using polarity mode is shown in the application section. Polarity mode is disabled by default. If in paired mode, the alternating polarity cycles will be added for each individual device output.


Figure 2. Sequence Showing Differential Output Format Options

## SYNC Signal

The SYNC output pin pulses high for the first MUX_SEL period in a MUX_SEL sequence beginning with the second MUX_SEL sequence and continuing for all subsequent cycles. This is useful for the user to ensure synchronization, to guarantee the right channels are sampled at the right time. The SYNC pin is particularly useful for applications where MUX_SEL is clocked continuously. When devices are used in paired mode, the SYNC signal for each device will be relative to its own position in the sequence.

## $I^{2} \mathrm{C}$ INTERFACE DETAILS

The NCP45495 uses a 400 kHz , slave mode FM I ${ }^{2} \mathrm{C}$ interface for communication with an $\mathrm{I}^{2} \mathrm{C}$ master. The purpose of the $\mathrm{I}^{2} \mathrm{C}$ interface is to provide access to
configuration settings. Data packets for the power monitor $\mathrm{I}^{2} \mathrm{C}$ interface are sent with a 7 bit slave address, an 8 bit register address, a read / write bit, and 8 bits of data. Acknowledge bits are used after the addresses and data as a handshake verification. The address for the device can be set to one of 4 available addresses using the ADRS[1:0] pins. If in paired mode, Device A's address must be different than Device B's address. Continuous read and continuous write $\mathrm{I}^{2} \mathrm{C}$ modes, or combined formats are not supported by the NCP45495. Bits are always sent out MSB first.
The ADRS[1:0] address mapping is as follows:

| ADRS[1] | ADRS[0] | Set Device Address |
| :---: | :---: | :---: |
| 0 | 0 | $0 \times 34$ |
| 0 | 1 | $0 \times 35$ |
| 1 | 0 | $0 \times 36$ |
| 1 | 1 | $0 \times 37$ |

It is recommended that all necessary registers are programmed while EN_B is held high. On the falling edge of EN_B, the programmed registers will be committed. On the first rising edge of the first MUX_SEL, the register setting will be effective. If register settings are programmed after EN_B has been asserted low, then the new settings will be effective at the beginning of the next MUX_SEL cycle. If register settings are programed while MUX_SEL is running, then the new settings will be effective on the rising edge of the first MUX_SEL of the next cycle.

The $\mathrm{I}^{2} \mathrm{C}$ bus can also be locked by setting the appropriate bits in the LOCK register. Setting bit 1 will lock the $I^{2} C$ interface to any write commands. In this configuration, the device will respond to read commands, but not to write commands. Setting bit 0 will lock the $\mathrm{I}^{2} \mathrm{C}$ interface completely. In this configuration the device will not respond to any $\mathrm{I}^{2} \mathrm{C}$ activity. The device must be power cycled to get out of either of these locked states.

## CONFIGURATION EXAMPLES

Figure 3 below shows an example of a register write. In this example, the address pins of the NCP45495 are tied low, selecting address $0 x 34$ as the slave address. The ACITVE_CHAN register is written with $0 x 89$, which will set channel 1 and channel 4 active, the ground reference is also enabled.


Figure 3. $\mathrm{I}^{2} \mathrm{C}$ Register Write Example
Figure 4 below shows an example of a register read. In this example, the master reads $0 \times 89$ from the ACTIVE_CHAN register.


Figure 4. $I^{2} \mathrm{C}$ Register Read Example

Table 8. TIMING REQURIEMENTS: $I^{2} \mathrm{C}$ INTERFACE

| Rating | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| SCL Clock Frequency | $\mathrm{F}_{12 \mathrm{C}}$ |  | 0.4 | MHz |
| Repeated hold time START condition (after this period, the first clock pulse is generated) | $\mathrm{t}_{\text {HD, STA }}$ | 0.26 | - | $\mu \mathrm{S}$ |
| Data hold time | $\mathrm{t}_{\text {HD, DAT }}$ | 0 | - | $\mu \mathrm{s}$ |
| LOW period of the SCL clock | t LOW | 0.5 | - | $\mu \mathrm{s}$ |
| HIGH period of the SCL clock | $\mathrm{t}_{\text {HIGH }}$ | 0.26 | - | $\mu \mathrm{S}$ |
| Setup time for repeated start condition | $\mathrm{t}_{\text {SU, STA }}$ | 0.26 | - | $\mu \mathrm{s}$ |
| Data setup time | $\mathrm{t}_{\text {SU; }}$ DAT | 50 | - | ns |
| Rise time for both SDA and SCL signals | $t_{r}$ | - | 120 | ns |
| Fall time of both SDA and SCL signals | $\mathrm{t}_{\mathrm{f}}$ | 18.1 | 120 | ns |
| Setup time for STOP condition | $\mathrm{t}_{\text {SU, STO }}$ | 0.26 | - | $\mu \mathrm{s}$ |
| Bus free time between a STOP and START condition | $\mathrm{t}_{\text {BUF }}$ | 0.5 | - | $\mu \mathrm{s}$ |
| Capacitive load for each bus line | $\mathrm{C}_{\mathrm{B}}$ | - | 550 | pF |
| Noise margin at the LOW level for each connected device | $\mathrm{V}_{\mathrm{nL}}$ | $0.1 * V_{\text {CC }}$ | - | V |
| Noise margin at the HIGH level for each connected device | $\mathrm{V}_{\mathrm{nH}}$ | $0.2 * V_{\mathrm{CC}}$ | - | V |
| Max ACK delay | $\mathrm{ACK}_{\text {MAX }}$ |  | 1 | ms |



Figure 5. $\mathrm{I}^{2} \mathrm{C}$ Bus Timing

| Write Data Example |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 1 bit | 7 bits | 1 bit | 1 bit | 8 bits | 1 bit | 8 bits | 1 bit | 1 bit |
| S | Slave Address | W=0 | A | Register Address | A | DATA | A/ $\bar{A}$ | P |


| Read Data Example |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 1 bit | 7 bits | 1 bit | 1 bit | 8 bits | 1 bit | 8 bits | 1 bit | 1 bit |
| S | Slave Address | $\mathrm{R}=1$ | A | Register Address | A | DATA | A/A | P |


| $\square$ From master to slave | -- $=$ acknowledge (SDA low) <br> $\square$ |
| :--- | :--- |
| $\square$ From slave to master | - $\mathrm{S}=$ START condition |
| $\square$ | P = STOP condition |

Figure 6. $\mathrm{I}^{2} \mathrm{C}$ Read / Write Protocol Format

Repeated Start format is also supported as shown below.


Figure 7. $I^{2}$ C Read with Repeated Start Format

## NCP45495

The purposes and utilities of all accessible registers in the NCP45495 are detailed below. Addresses and bit assignments are explained.

Table 9. REGISTER MAP

| Register Address | Register Name | Bits | R/W | Description | Default <br> Setting | New Value Takes Effect |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 0x00 | VendorID | 7:0 | R | onsemi Specific ID | 0x4F | N/A |
| $0 \times 01$ | DeviceID | 7:0 | R | NCP45495 Specific Device ID | 0x2D | N/A |
| $0 \times 04$ | ACTIVE_CHAN | 7 | R/W | Enable Ground Reference | 0 | At next MUX_SEL cycle |
|  |  | 5 | R/W | Enable iMon Channel 2 | 0 | At next MUX_SEL cycle |
|  |  | 4 | R/W | Enable iMon Channel 1 | 0 | At next MUX_SEL cycle |
|  |  | 3 | R/W | Enable Channel 4 | 1 | At next MUX_SEL cycle |
|  |  | 2 | R/W | Enable Channel 3 | 1 | At next MUX_SEL cycle |
|  |  | 1 | R/W | Enable Channel 2 | 1 | At next MUX_SEL cycle |
|  |  | 0 | R/W | Enable Channel 1 | 1 | At next MUX_SEL cycle |
| 0x05 | MUX_SEL_SKIP <br> (set as 0x00 if operating in single device mode) | 7:4 | R/W | Pulses to skip at the start of the MUX_SEL cycle (skipping pulses at the beginning defines device as device $B$ in paired mode) | 0x0 | At next MUX_SEL cycle |
|  |  | 3:0 | R/W | Pulses to skip at the end of the MUX_SEL cycle (skipping pulses at the end defines device as device A in paired mode) | $0 \times 0$ | At next MUX_SEL cycle |
| $0 \times 06$ | ALTERNATING_MODE | 7:7 | R/W | Ob1: Use Alternating Polarity Mode <br> ObO: Alternating Polarity Mode Disabled | 0 | At next MUX_SEL cycle |
| $0 \times 07$ | DIFF_AMP_OFFSET | 1:0 | R/W | 0b11: -375 mV <br> 0b10: - 350 mV <br> 0b01: -325 mV <br> Ob00: 0 mV | 0x0 | Immediately |
| $0 \times 08$ | DIFF_AMP_CM <br> Note: Differential output accuracy not guaranteed with $\mathrm{V}_{\mathrm{CMR}}$ below 575 mV . (Codes 0x0, 0x1, 0x2) | 3:0 | R/W | Ob1111: 875 mV 0b1110: 850 mV 0b0111: 675 mV 0b0100: 600 mV 0b0011: 575 mV | $\begin{gathered} 0 \times 7 \\ (675 \mathrm{mV}) \end{gathered}$ | Immediately |
| 0x0F | TIMEOUT | 7:7 | R/W | 0b1: Disable Timeout <br> ObO: Timeout Active | 0 | Immediately |
| $0 \times 10$ | BUS_GAIN1 | 5:1 | R/W | (Register contents: See Table 7) | $0 \times 00$ | Immediately |
| $0 \times 11$ | BUS_GAIN2 | 5:1 | R/W | 0x3E: 1/4 | (1/64) |  |
| $0 \times 12$ | BUS_GAIN3 | 5:1 | R/W |  |  |  |
| $0 \times 13$ | BUS_GAIN4 | 5:1 | R/W |  |  |  |
| 0x20 | SHUNT_GAIN1 | 5:1 | R/W | (Register contents: See Table 6) | $0 \times 00$ | Immediately |
| 0x21 | SHUNT_GAIN2 | 5:1 | R/W | 0x3E: 24x <br> 0x00: $2 x$ | (2x) |  |
| $0 \times 22$ | SHUNT_GAIN3 | 5:1 | R/W |  |  |  |
| 0x23 | SHUNT_GAIN4 | 5:1 | R/W |  |  |  |
| 0x24 | LOCK | 1 | R/W | Lock ${ }^{2} \mathrm{C}$ interface writes | 0 | Immediately |
|  |  | 0 | R/W | Lock ${ }^{2} \mathrm{C}$ interface reads / writes | 0 | Immediately |

APPLICATIONS DIAGRAMS


Figure 8. Stand Alone Device Typical Application Diagram


Figure 9. Stand Alone Signal Characteristics with all 4 Channels Activated
cc $\qquad$

Figure 10. Stand Alone Signal Characteristics with IMON 1, IMON2, and Ground Reference Bits Set and all Channels Activated


Figure 11. Stand Alone Signal Characteristics with ALTERNATING_MODE Bit Set and all Channels Activated


Figure 12. Six-Channel Paired Devices Connection Diagram


Figure 13. Six-Channel Paired Device Signal Characteristics with 6 Channels Activated
The following example shows the output sequence when all channels are active with a ground reference and alternating mode enabled in paired mode. The register settings for each device are shown below.

| DEVICE A ( $\mathbf{I}^{2} \mathbf{C}$ address: $\mathbf{0 \times 3 4 )}$ |  | DEVICE B ( ${ }^{2} \mathbf{C}$ Address: $0 \times 35$ ) |  |
| :---: | :---: | :---: | :---: |
| Register Address | Register Address | Register Address | Register Setting |
| $0 \times 04$ | $0 \times 04$ | $0 \times 04$ | $0 \times 5 \mathrm{~F}$ |
| $0 \times 05$ | $0 \times 05$ | $0 \times 05$ | $0 \times 07$ |
| $0 \times 06$ | $0 \times 06$ | $0 \times 06$ | $0 \times 80$ |


| Clock Cycle | Diff Output (Device A) | Diff Output (Device B) |
| :---: | :---: | :---: |
| 0 | High Z | High Z |
| 1 | Ch 1 Bus Voltage | High Z |
| 2 | Ch 1 Shunt Current | High Z |
| 3 | Ch 2 Bus Voltage | High Z |
| 4 | Ch 2 Shunt Current | High Z |
| 5 | Ch 3 Bus Voltage | High Z |
| 6 | Ch 3 Shunt Current | High Z |
| 7 | Ch 4 Bus Voltage | High Z |
| 8 | Ch 4 Shunt Current | High Z |
| 9 | iMon1 | High Z |
| 10 | iMon2 | High Z |
| 11 | Ref GND | High Z |
| 12 | High Z | Ch 1 Bus Voltage |
| 13 | High Z | Ch 1 Shunt Current |
| 14 | High Z | Ch 2 Bus Voltage |
| 15 | High Z | Ch 2 Shunt Current |
| 16 | High Z | Ch 3 Bus Voltage |
| 17 | High Z | Ch 3 Shunt Current |
| 18 | High Z | Ch 4 Bus Voltage |
| 19 | High Z | Ch 4 Shunt Current |
| 20 | High Z | iMon1 |
| 21 | High Z | iMon2 |
| 22 | High Z | Ref GND |
| 23 | Ch 1 Bus Voltage Reversed | High Z |
| 24 | Ch 1 Shunt Current Reversed | High Z |
| 25 | Ch 2 Bus Voltage Reversed | High Z |
| 26 | Ch 2 Shunt Current Reversed | High Z |
| 27 | Ch 3 Bus Voltage Reversed | High Z |
| 28 | Ch 3 Shunt Current Reversed | High Z |
| 29 | Ch 4 Bus Voltage Reversed | High Z |
| 30 | Ch 4 Shunt Current Reversed | High Z |
| 31 | iMon1 Reversed | High Z |
| 32 | iMon2 Reversed | High Z |
| 33 | Ref GND Reversed | High Z |
| 34 | High Z | Ch 1 Bus Voltage Reversed |
| 35 | High Z | Ch 1 Shunt Current Reversed |
| 36 | High Z | Ch 2 Bus Voltage Reversed |
| 37 | High Z | Ch 2 Shunt Current Reversed |
| 38 | High Z | Ch 3 Bus Voltage Reversed |
| 39 | High Z | Ch 3 Shunt Current Reversed |
| 40 | High Z | Ch 4 Bus Voltage Reversed |
| 41 | High Z | Ch 4 Shunt Current Reversed |
| 42 | High Z | iMon1 Reversed |
| 43 | High Z | iMon2 Reversed |
| 44 | High Z | Ref GND Reversed |
| 45 | Ch 1 Bus Voltage | High Z |

## AUXILIARY FUNCTIONS

Bus Comparator (BV_OK): The BV_OK pin provides a real-time indication that $\mathrm{V}_{\mathrm{CC}}$ and all bus voltages (as measured on the BV_INx pins) are valid. BV_OK remains low until all used BV_INx pins are above a user-defined threshold voltage. The BV_OK threshold is set by an external resistor divider on the BV_REF pin. The internal BV_OK comparator has built in hysteresis of $10 \%$ to prevent chatter as voltage busses come up. All channels specified in the ACTIVE_CHAN register will be represented. If desired, the user can use the SKIP pin to modify the logic as shown in the corresponding table ( $\mathrm{H}=$ high, $\mathrm{L}=$ low, $\mathrm{Z}=$ tristate, $\mathrm{X}=$ don't care). The SKIP pin can also be used to hold BV_OK = L in the absence of $\mathrm{V}_{\mathrm{CC}}$.

| VCC | EN_B | VB_INx | SKIP | BV_OK | Notes |
| :--- | :--- | :--- | :--- | :--- | :--- |
| L | L | X | L | open <br> drain | No Power <br> Provided to Part |
| L | L | X | H | L | SKIP Pin Provides <br> Power Needed to <br> Hold BV_OK Low |
| H | H | X | L | open <br> drain | Standby Mode |
| H | H | X | H | L | Standby Mode |
| H | Z/L | L | H | L | Functional or <br> Limited Mode |
| H | Z/L | H | H | open <br> drain | Functional or <br> Limited Mode |
| H | Z/L | X | L | open <br> drain | Functional or <br> Limited Mode |

Reset/Timeout: If the timeout is enabled, holding the MUX_SEL pin HIGH or LOW linger then $45 \mu$ s will reset to the beginning of the MUX_SEL sequence. If the timeout has been disabled, then the MUX_SEL must cycle through all set channels to return to the beginning of the sequence. Toggling the EN_B pin will also reset the sequence back to the beginning.
Bandgap Reference: The BG_REF_OUT pin provides a high-accuracy voltage that can be used to generate the BV_REF voltage for the BV_OK comparators.

Enable Function: The EN_B pin controls device operation according to the corresponding table.

EN_B LOGIC

| Level | Device Operation |
| :---: | :--- |
| LOW | Fully Functional |
| Tri-state <br> (floating) | Limited Function: BG_REF_OUT is valid, BV_OK <br> comparators and output are functional. All other <br> functions to be disabled. DIFF_OUT to be Hi-Z <br> and multiplexer select logic is held in reset. |
| HIGH | Standby: Power down state. Nothing is active. |

Input Filtering:
If additional filtering is needed on the input bus lines, external filtering can be added as shown below.


Mismatch between the $2 \mathrm{R}_{\mathrm{F}}$ values will contribute to the overall measurement offset error. To avoid this, the tolerance of external $\mathrm{R}_{\mathrm{F}}$ resistors should be $<1 \%$. External $\mathrm{R}_{\mathrm{F}}$ values should not exceed $20 \mathrm{k} \Omega$.

## Layout Considerations

Sensitive signals that require special attention in board layout include the channel inputs (IN_N, IN_P, and BV_IN signals), the differential output signals, and the MUX_SEL signal. The IN_N and IN_P signals require a direct kelvin connection to the leads of the sense resistor to avoid parasitic trace resistance affecting the shunt current measurement. This direct connection is shown below. The sense resistors and connections from source to load for each channel need to be large enough to accommodate the expected high load currents.


Care should be taken to keep DIFF_OUT_P and DIFF_OUT_N matched. As a differential pair, any noise introduced to the pair will be common and will be rejected if the signals are close together and matched in length. Care should be taken to keep the MUX_SEL line isolated from other dynamically changing signals.

## Unused Channels

Unused channels can be disabled by setting Register 0x04 over $\mathrm{I}^{2} \mathrm{C}$. The following table details the recommended connections for unused pins.

| Unused Pins | Connection |
| :---: | :--- |
| BV_INx | Connect to a BV_IN pin of previous channel |
| IN_Px | Connect to $V_{C C}$ voltage or higher, or float, or <br> ground |
| IN_Nx | Connect to $V_{C C}$ voltage or higher, or float, or <br> ground |
| IMONx | Float or ground |
| SYNC | Float |



QFN32 4x4, 0.4P
CASE 485CD
ISSUE A
DATE 09 OCT 2012
NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
CONTROLLING DIMENSION: MILLIMETERS.
2. DIMENSION b APPLIES TO PLATED TERMINAL

AND IS MEASURED BETWEEN 0.15 AND 0.30 Mm FROM TERMINALTIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

| DIM | MILLIMETERS |  |
| :---: | :---: | :---: |
|  | MIN | MAX |
| A | 0.80 | 1.00 |
| A1 | 0.00 | 0.05 |
| A3 | 0.20 | REF |
| b | 0.15 | 0.25 |
| D | 4.00 | BSC |
| D2 | 2.60 | 2.80 |
| E | 4.00 | BSC |
| E2 | 2.60 | 2.80 |
| e | 0.40 | BSC |
| K | 0.30 | REF |
| K2 | 0.45 | REF |
| L | 0.25 | 0.45 |
| L1 | --- | 0.15 |

GENERIC MARKING DIAGRAM*

| XXXXXX <br> XXXXXX <br> ALYW. <br> $\bullet$ |
| :---: |

XXXXX = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

- = Pb-Free Package
(Note: Microdot may be in either location)
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

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